

FRED Ultrafast Soft Recovery Diode 60A × 2 / 600V



FEATURES

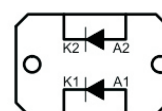
- Fast recovery time characteristic
- Electrically isolated base plate
- Large creepage distance between terminal
- Simplified mechanical designs, rapid assembly
- Compliant to RoHS
- Designed and for industrial level
- Planar FRED Chip



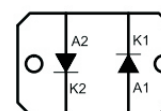
DESCRIPTION

This SOT-227 modules with FRED rectifier are available in two basic configurations. They are the antiparallel and the parallel configurations. The antiparallel configuration NST120F06-A is used for simple series rectifier and high voltage application. The parallel configuration NST120F06 is used for simple parallel rectifier and high current application. The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built. These modules are intended for general applications such as power supplies, battery chargers, electronic welders, motor control, DC chopper, and inverters.

CIRCUIT CONFIGURATION



Parallel
NST120F06



Anti-Parallel
NST120F06-A

APPLICATIONS

- Switching power supplies
- Inverters
- Motor controllers
- Converters
- Snubber diodes
- Uninterruptible power supplies (UPS)
- Induction heating
- High speed rectifiers

PRODUCT SUMMARY

V_R	600 V
V_F (typical) at 125 °C	1.05V
Q_{rr} (typical)	220nC
I_{RRM} (typical)	4A
t_{rr} (typical)	40 ns
$I_{F(DC)}$ at T_C per diode	60A at 106 °C

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	V_R		600	V
Maximum continuous forward current per leg per module	I_F	$T_c = 106\text{ °C}$	60 120	A
Single pulse forward current	I_{FSM}	$T_J = 25\text{ °C}$	600	
RMS isolation voltage, any terminal to case	V_{ISO}	$t = 1\text{ minute}$	2500	V
Maximum power dissipation	P_D	$T_c = 25\text{ °C}$ $T_c = 100\text{ °C}$	180 125	W
Operating junction and storage temperature range	T_J, T_{Stg}		- 55 to 175	°C

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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	600	-	-	V
Maximum forward voltage	V _{FM}	I _F = 60 A	-	1.26	1.50	
		I _F = 120 A	-	1.55	1.80	
		I _F = 60 A, T _J = 125 °C	-	1.05	1.30	μA
Maximum reverse leakage current	I _{RM}	V _R = V _R rated	-	2	20	
		T _J = 125 °C, V _R = V _R rated	-	-	500	
Junction capacitance	C _J	V _R = 200V	90			pF

DYNAMIC RECOVERY CHARACTERISTICS PERLEG (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t _{rr}	I _F = 0.5A, I _R = 1.0A, I _{RR} = 250mA (RG#1 CKT)	-	55	65	ns
		I _F = 1.0 A, dI _F /dt = -100 A/μs, V _R = 30 V, T _J = 25 °C	-	40	-	
	t _{rr1}	T _J = 25 °C	-	130	-	
	t _{rr2}	T _J = 125 °C	-	170	-	
Reverse recovery time	I _{RRM1}	T _J = 25 °C	-	4	-	A
	I _{RRM2}	T _J = 125 °C	-	10	-	
Reverse recovery time	Q _{rr1}	T _J = 25 °C	-	220	-	nC
	Q _{rr2}	T _J = 125 °C	-	920	-	

THERMAL - MECHANICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)					
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS
Junction to case, single leg conducting	R _{thJC}	-	-	0.60	°C/W K/W
Junction to case, both legs conducting		-	-	0.30	
Case to sink, flat, greased surface	R _{thCS}	-	0.05	-	
Isolation RMS voltage (50~60Hz sinusoidal waveform from terminals to mounting base for 1 Min.)	V _{ISO}	2500	-	-	V
Weight		-	30	-	g
Mounting torque		-	-	1.1	N·m
				10	lb·in

Fig.1a Maximum effective transient thermal impedance, junction-to-case vs. pulse duration

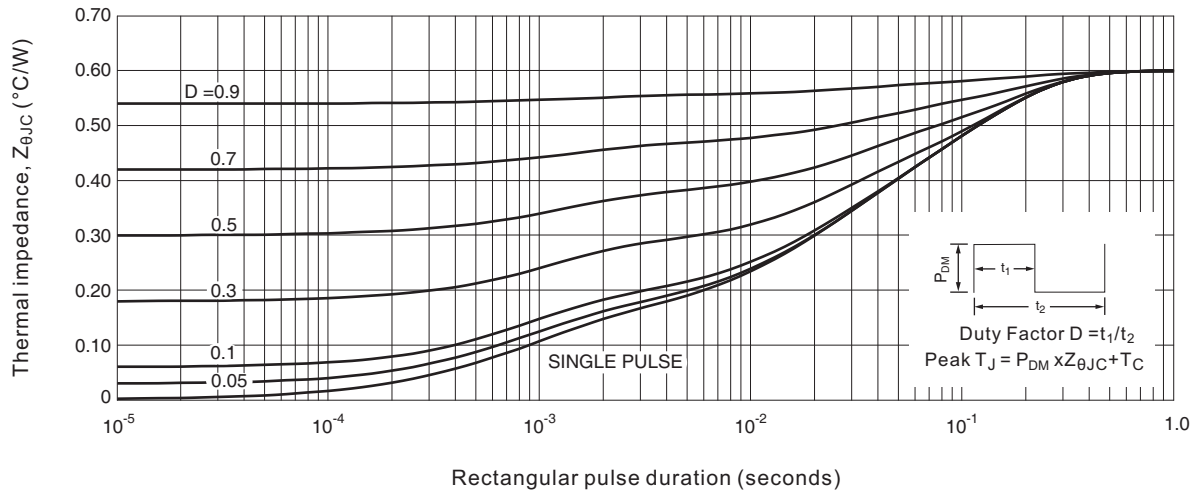


Fig.1b Transient thermal impedance model

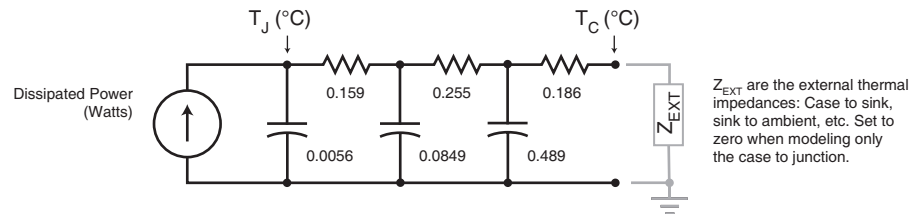


Fig.2 Forward current vs. forward voltage

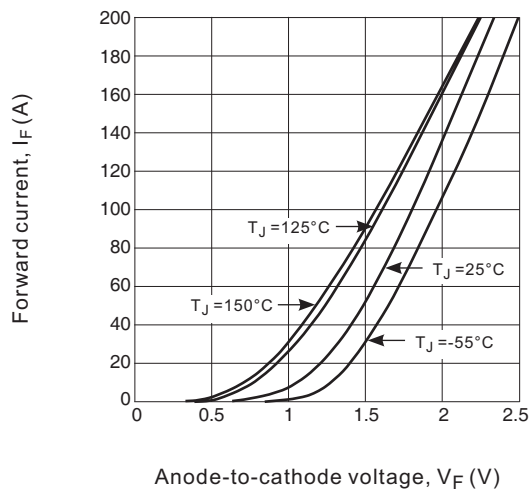
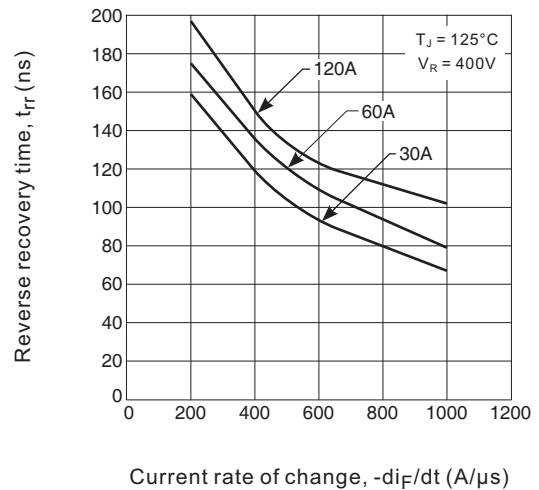


Fig.3 Reverse recovery time vs. current rate of change



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Fig.4 Reverse recovery charge vs. current rate of change

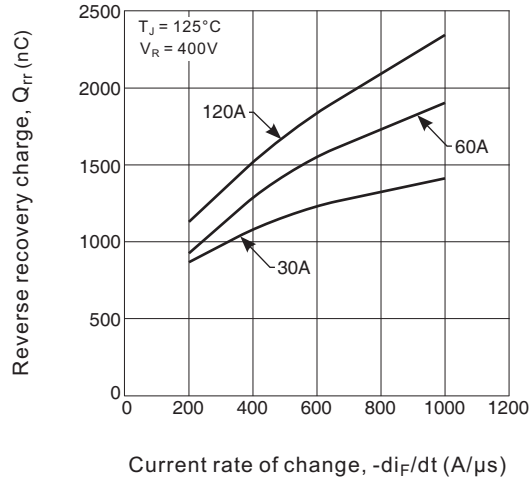


Fig 5. Reverse recovery current vs. current rate of change

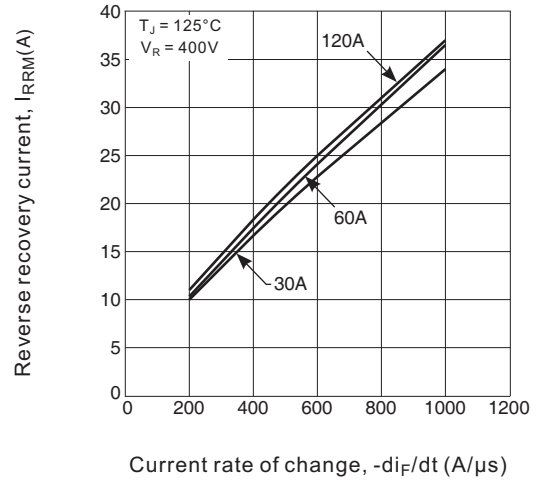


Fig6. Dynamic parameters vs. junction temperature

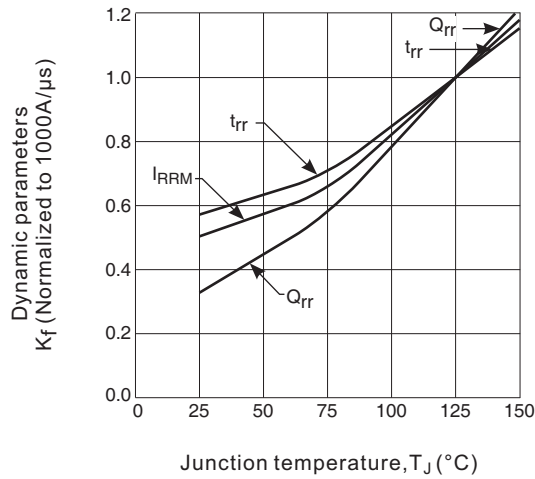


Fig.7 Maximum average forward current vs. case temperature

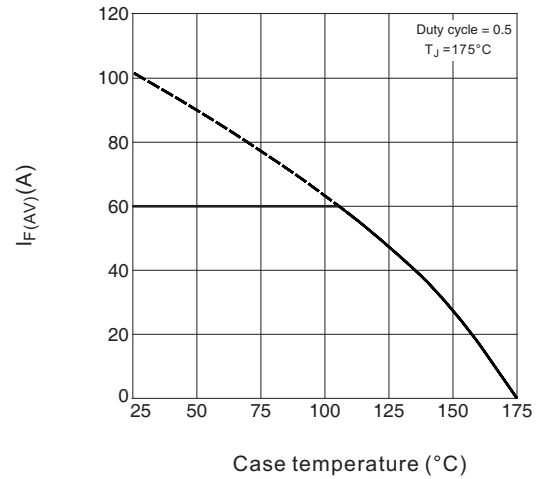


Fig.8 Junction capacitance vs. reverse voltage

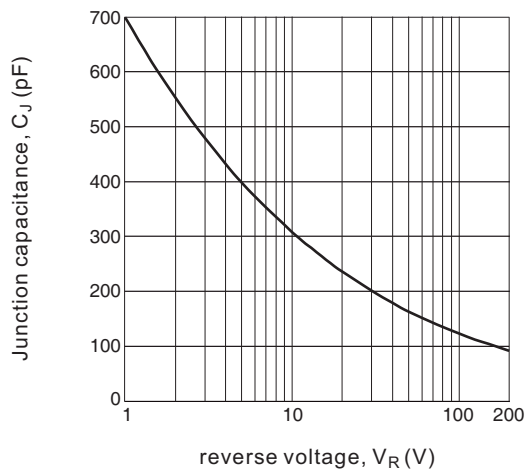
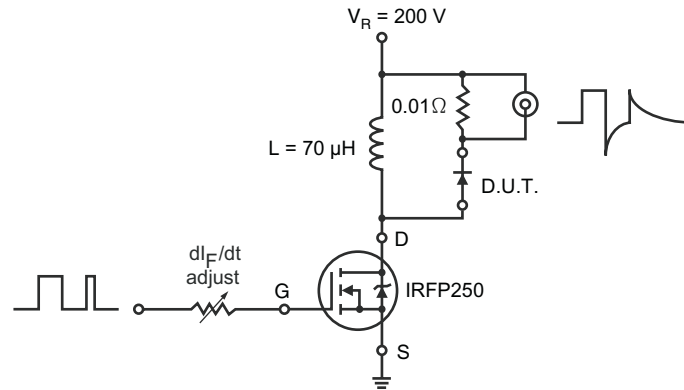
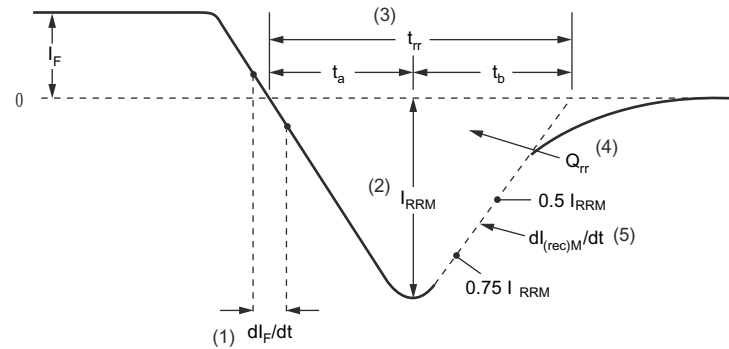


Fig.9 Reverse recovery parameter test circuit

Fig.10 Reverse recovery waveform and definitions


(1) dl_F/dt - rate of change of current through zero crossing

(2) I_{RRM} - peak reverse recovery current

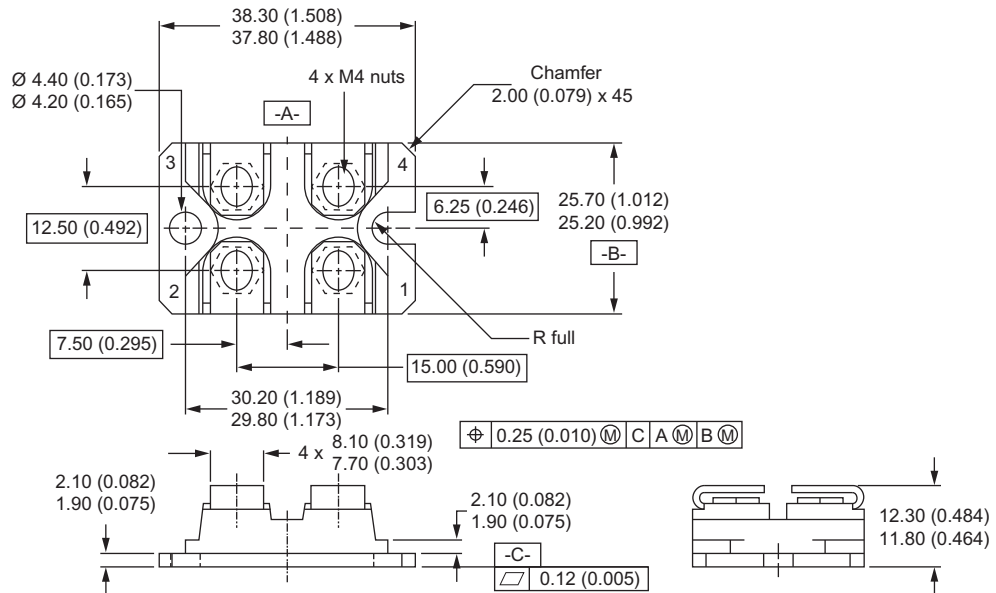
(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.50 I_{RRM}$ extrapolated to zero current.

(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dl_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

SOT-227



All dimensions in millimeters (inches)

Notes

- Dimensioning and tolerancing per ANSI Y14.5M-1982
- Controlling dimension: millimeter

ORDERING INFORMATION TABLE

Device code	N	ST	120	F	06	—	A
	①	②	③	④	⑤		⑥

- 1 - Nell High Power Products
- 2 - Package indicator (SOT-227)
- 3 - Current rating (120 = 120A, 60A x 2)
- 4 - F = FRED family
- 5 - Voltage rating (06 = 600 V)
- 6 - Circuit type, A for Anti-Parallel type
Blank for parallel type.